



**DMG4710SSS** 

#### N-CHANNEL ENHANCEMENT MODE MOSFET WITH SCHOTTKY DIODE

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> MAX	I <sub>D</sub> MAX T <sub>A</sub> = +25°C (Note 6)
30V	12.5mΩ @ V <sub>GS</sub> = 10V	11.7A
	14.8mΩ @ V <sub>GS</sub> = 4.5V	10.8A

#### **Features**

- DIOFET utilizes a unique patented process to monolithically integrate a MOSFET and a Schottky in a single die to deliver:
  - Low R<sub>DS(ON)</sub> minimizes conduction losses
  - Low V<sub>SD</sub> reducing the losses due to body diode conduction
  - Low Q<sub>rr</sub> lower Q<sub>rr</sub> of the integrated Schottky reduces body diode switching losses
  - Low gate capacitance  $(Q_g/Q_{gs})$  ratio reduces risk of shootthrough or cross conduction currents at high frequencies
  - Avalanche rugged IAR and EAR rated
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

# **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

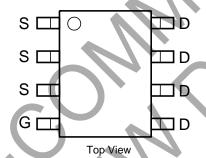
- DC-DC Converters
- Power Management Functions

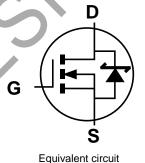
### **Mechanical Data**

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Weight: 0.072 grams (Approximate)



Top View





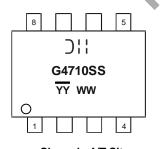
Ordering Information (Note 4)

Part Number	Case	Packaging
DMG4710SSS-13	SO-8	2500 / Tape & Reel

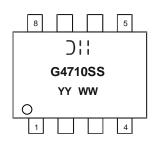
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

# **Marking Information**



Chengdu A/T Site



Shanghai A/T Site

);; = Manufacturer's Marking G4710SS = Product Type Marking Code YYWW = Date Code Marking YY or  $\overline{YY}$  = Year (ex: 18 = 2018) WW = Week (01 to 53)

YY = Date Code Marking for SAT (Shanghai Assembly/ Test Site) YY = Date Code Marking for CAT (Chengdu Assembly/ Test Site)



**DMG4710SSS** 

### Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Character	Symbol	Value 30	Unit V		
Drain-Source Voltage	V <sub>DSS</sub>				
Gate-Source Voltage			V <sub>GSS</sub>	±12	V
Continuous Drain Current (Note 5) V <sub>GS</sub> = 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +85^{\circ}C$	I <sub>D</sub>	8.8 6.3	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	t ≤ 10s	$T_A = +25^{\circ}C$ $T_A = +85^{\circ}C$	I <sub>D</sub>	11.7 8.5	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = 4.5V	t ≤ 10s	$T_A = +25^{\circ}C$ $T_A = +85^{\circ}C$	ID	10.8 7.8	А
Pulsed Drain Current (Note 7)			I <sub>DM</sub>	90	Α
Avalanche Current (Notes 7 & 8)	I <sub>AR</sub>	13	Α		
Repetitive Avalanche Energy (Notes 7 & 8) L = 0.3mH			E <sub>AR</sub>	25.4	mJ

# **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Power Dissipation (Note 5)		P <sub>D</sub>	1.54	W
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 5)		R <sub>θJA</sub>	81	°C/W
Power Dissipation (Note 6)		P <sub>D</sub>	2.8	W
Thermal Resistance, Junction to Ambient @ T <sub>A</sub> = +25°C (Note 6)		Reja	45	°C/W
Operating and Storage Temperature Range	411.	TJ, T <sub>STG</sub>	-55 to +150	°C

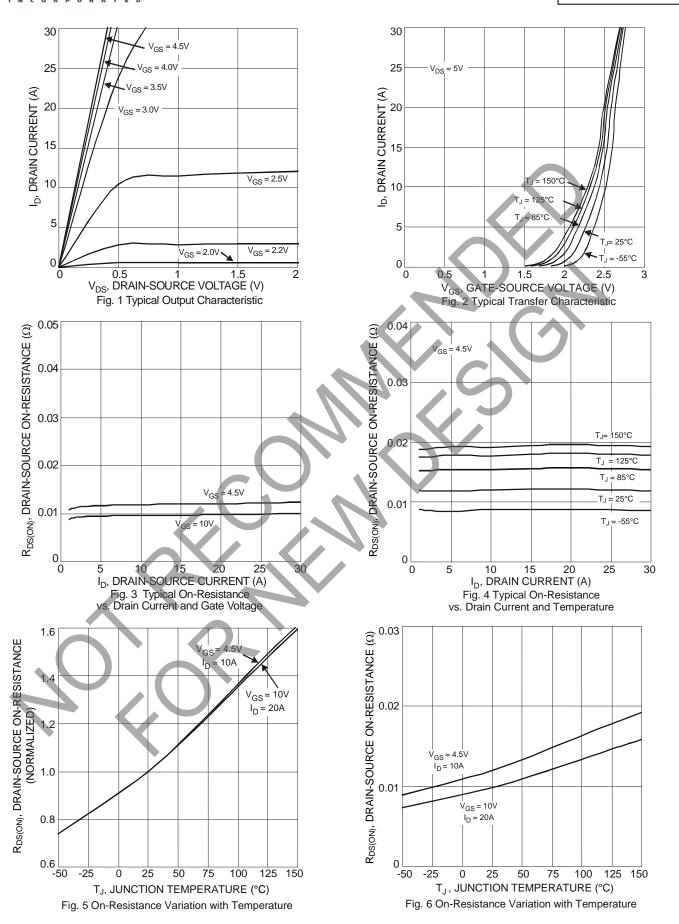
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)	_						
Drain-Source Breakdown Voltage		30	-	-	V	$V_{GS} = 0V$ , $I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	-	-	0.1	mA	$V_{DS} = 30V$ , $V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	1	-	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.0	-	2.3	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance	Program	-	9.5	12.5	mΩ	$V_{GS} = 10V, I_D = 11.7A$	
Static Drain-Source Off-Resistance	R <sub>DS(ON)</sub>	-	11.5	14.8	11152	$V_{GS} = 4.5V, I_D = 10.8A$	
Forward Transfer Admittance	Y <sub>fs</sub>	-	22	-	S	$V_{DS} = 5V, I_{D} = 11.7A$	
Diode Forward Voltage	V <sub>SD</sub>	-	0.38	0.6	V	$V_{GS} = 0V, I_{S} = 1A$	
Maximum Body-Diode + Schottky Continuous Current	Is	-	-	5	Α	-	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	-	1849	-	pF	\/ 45\/ \/ 0\/	
Output Capacitance	Coss	-	158	-	pF	$V_{DS} = 15V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	$C_{rss}$	-	123	-	pF	1 – 1.000112	
Gate Resistance	$R_g$	0.54	2.68	4.82	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	$Q_{g}$	-	18.5	-	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	$Q_g$	-	43	1	nC	V <sub>DS</sub> = 15V, I <sub>D</sub> = 11.7A	
Gate-Source Charge	$Q_{gs}$	-	4.7	-	nC	V <sub>DS</sub> = 15V, I <sub>D</sub> = 11.7A	
Gate-Drain Charge	$Q_{gd}$	-	4.0	1	nC		
Turn-On Delay Time	t <sub>D(ON)</sub>	-	6.62	-	ns		
Turn-On Rise Time	t <sub>R</sub>	-	8.73	-	ns	$V_{GS} = 10V, V_{DS} = 10V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	-	36.41	-	ns	$R_g = 3\Omega$ , $R_L = 1.2\Omega$	
Turn-Off Fall Time	t <sub>F</sub>	-	4.69	-	ns	<u> </u>	

Notes:

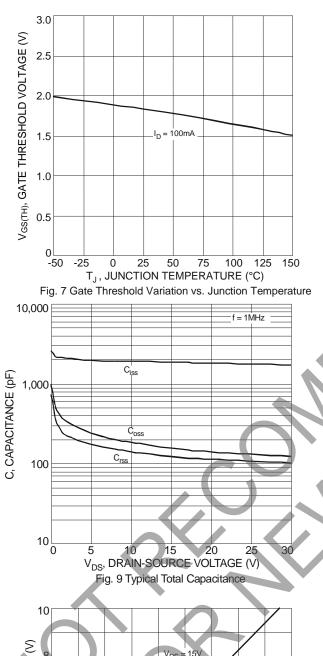
- 5. Device mounted on FR-4 PCB with minimum recommended pad layout. The value in any given application depends on the user's specific board design.
  6. Device mounted on 1" x 1" FR-4 PCB with high coverage 1 oz. Copper, single sided, device is measured at t ≤ 10s.
- 7. Repetitive rating, pulse width limited by junction temperature.
- 8.  $I_{AR}$  and  $E_{AR}$  ratings are based on low frequency and duty cycles to keep  $T_J = +25$ °C.
- 9. Short duration pulse test used to minimize self-heating effect.
- 10. Guaranteed by design. Not subject to production testing.

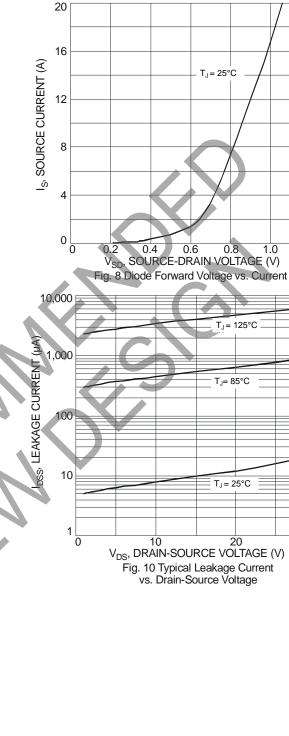
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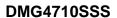
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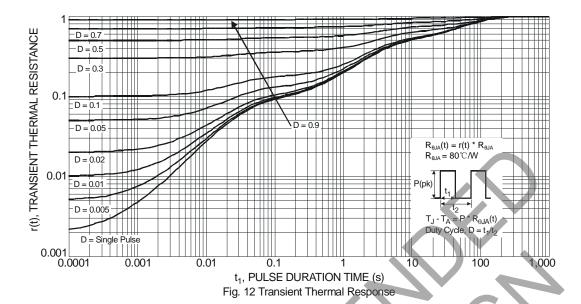


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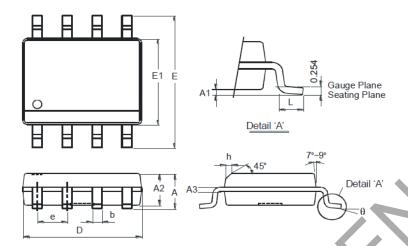






# **Package Outline Dimensions**

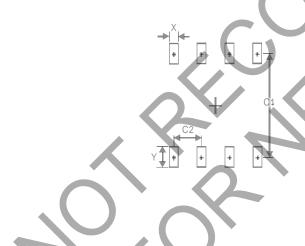
Please see http://www.diodes.com/package-outlines.html for the latest version.



SO-8					
Dim	Min	Max			
Α	-	1.75			
A1	0.10	0.20			
A2	1.30	1.50			
A3	0.15	0.25			
b	0.3	0.5			
D	4.85	4.95			
E	5.90	6.10			
E1	3.85	3.95			
е	1.27 Typ				
h		0.35			
L	0.62	0.82			
θ	ô	8°			
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
Х	0.60
Υ	1.55
C1	5.4
C2	1 27



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